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Study of vacancy-(H,B,C,N,O) clusters in Al using DFT and statistical approaches: Consequences on solubility of solutes

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ABSTRACT

This article is a study of the solubility of interstitial atoms in aluminum using a multi-scale approach. We focused on hydrogen, boron, carbon, nitrogen and oxygen atoms (labeled X). We studied isolated atoms as well as the possible formation of clusters with and without vacancies (*V*), i.e., X_m , VX_m and V_2X_m (m ≥ 0). Formation and segregation energies are first obtained using first-principles calculations, subsequently, a statistical approach is employed in order to evaluate the concentration of impurities and defects according to the temperature. For instance, we find that, in solute solution, H, N and O atoms prefer to be located in tetrahedral sites, and C and B atoms in octahedral sites. The chemical and energetic interactions between the interstitials, the metal and the vacancies are consequently presented and analyzed in detail. Results show that certain species prefer to interact with themselves, thus forming X_m clusters, and others with vacancies, thus forming stable VX_m clusters in the metal. Using a statistical approach, we finally discuss the formation of clusters according to the temperature solution of clusters according to the temperature and the X concentration. At low and intermediate temperatures (below 600 K), we found that the atoms prefer to form clusters rather than stay isolated in aluminum. We show that H and B atoms are the only elements likely to increase vacancy concentration.

1. Introduction

It has been shown in earlier works [1-5] that the presence of interstitials, even in undetectable quantities, can have a significant impact on the concentration of defects (clusters, cavities, etc.) present in metals, especially on vacancy concentration. Therefore, the concentration of interstitial elements and point defects can be significantly different from what is expected with conventional laws (like Sieverts' law [6]). For instance, in the case of nickel [1,7], it has been shown that O and H atoms can form high concentrations of clusters ($V_n X_m$, composed of n V vacancies and m X atoms), especially at low and intermediate temperatures. In the case of iron, Schuler et al. [4] have shown that C atoms can form V₂C₂ clusters in a non-negligible concentration. The use of relevant multi-scale approaches has also clearly proved [1,4,8] that DFT simulations alone are not able to analyze and interpret these mechanisms. It has been shown that the energy associated with cluster formation in the metal can strongly reduce the formation of vacancies, thus

increasing the concentration of defects in the system, consequently enhancing the processes of diffusion of all species in the metal.

In the present work, we discuss the insertion of five interstitial elements in fcc-Al: hydrogen, boron, carbon, oxygen and nitrogen. Their interactions with vacancies and their capacity to form clusters in aluminum are thus discussed. The formation of H and He clusters in aluminum has been partly discussed in the literature: either only VX_m clusters were considered [5,8–10], or the multi-scale approach was not aimed at discussing the actual influence of cluster concentration on vacancy concentration [11]. In a recent work [12], diffusion mechanisms of interstitial elements were presented without discussing the interactions between Al and interstitials. This manuscript is aimed at filling these gaps as well as studying the case of other interstitials.

From an experimental standpoint, studies show that the maximum solubility of interstitial species in aluminum strongly depends on experimental conditions as well as on the specie. It has been shown that the limit of solubility is low in the case of H, C, N, O and B atoms, even at high temperature. The content of nitrogen dissolved in the Al matrix is thus probably low. But according to Wriedt's [13] observations, this experimental data has little credibility. The exact N concentration is therefore unknown but can be

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considered relatively low. When the fugacity of N₂ becomes too "high" (10^{-20} Pa at 933 K [13]), an AlN phase, with a wurtzite type structure, is formed. As for nitrogen, the Al-O phase diagram [14] is composed of only one intermediate structure between Al-fcc and O_2 gas: alumina α -Al₂O₃ (with many additional allotropic structures). The O content in the metal is likewise supposed very low. The solid solubility of C atoms is also low, it is estimated at 400-800 appm [15]. However, Okamoto [16] explains that this concentration value is probably overestimated by at least one order of magnitude. In the case of hydrogen, the study of Al-H system [17] also shows that hydrogen barely dissolves in aluminum: 15-20 appm near the melting point. Finally, the boron concentration is also low: a maximum solid solubility of 45 appm of B in Al has been measured at 933 K, see the Al-B system [18]. In summary, the concentration of interstitial elements can be considered ranging from 10 to 100 appm.

This work aims at evaluating solubility energies of these species and identifying the forms under which they are dissolved in the metal as a function of the temperature (T). The mechanisms of diffusion and the thermodynamics should vary depending on whether they are free or form clusters. As a first-order approximation, we used a multi-physics approach coupling first-principles simulations and a statistical model. At the atomic scale, simulations allow modeling free species (X) and different types of clusters (X_m , VX_m and V_2X_m) in the metal. It is not an exhaustive study, not all configurations were considered. However, the current work provides a broad overview of the interactions between X atoms and Al. We calculated the formation energies of these clusters and analyzed their chemical properties. Subsequently, by using these accurate values in the statistical model, we computed the distribution and concentration of the different clusters as a function of T and the total concentration of interstitials in the metal.

The remainder of this paper is organized as follows. Section 2 summarizes the DFT parameters and briefly describes the model that was used. In part 3, we discuss the insertion of the five species in the light of DFT results. The formation of different types of clusters is then presented (sections 4-6). We will conclude (section 7) with a discussion on the concentration and fraction of clusters in the metal using a statistical approach.

2. Computational details

First-principles calculations were performed with the density functional theory (DFT) using VASP (Vienna *ab initio* simulation package [19]). We used the Perdew-Burke-Ernzerhof (PBE [20]) functional. Projector augmented wave (PAW) pseudo-potentials [21] were employed to describe atoms. As aluminum is not magnetic, the magnetic moment was not taken into account. In Appendix A, we report some results about several stable structures used hereinafter, especially reference states. Experimental structures are remarkably well reproduced by the DFT.

To study $V_n X_m$ clusters, simulations were carried out on a large super-cell (3 × 3 × 3, that which corresponds to 108 atoms per unitcell) with full periodic boundary conditions. The inter-atomic forces were fully relaxed and all calculations were performed at zero pressure. We made sure that atomic forces were always smaller than 0.01 eV/Å on the atoms. The plane-wave cut-off energy was set to 600 eV, and 8 × 8 × 8 Monkhorst-Pack mesh grids [22] were used to sample the first-Brillouin zones. With these criteria we obtain converged formation and segregation energies (<2–3 meV). To compute frequencies, we used the finite displacement method on super-cells. As a first-order approximation, only frequencies of *X* atoms were computed, we thus neglect the effects of the insertion on Al frequencies (values reported in tables). However, due to the strong coupling between Al and X frequencies, we calculated the full inter-atomic force constants on $2 \times 2 \times 2$ super-cells, displacing only non-equivalent atoms along non-equivalent directions according to the symmetry of the system. The *phonopy* package [23] was used to generate finite displacements according to the symmetry of each structure, it was then used to analyze, plot vibrational properties (phonon dispersion curves and density of states, not shown here) and compute vibrational free energies.

To evaluate the distribution and concentration of clusters, we used an approach similar to the one described by Dome et al. [1]. For each type of cluster *i* of V_pX_m composed of *m* X atoms and *p* vacancies, its concentration $(C_i[V_pX_m])$ is related to its formation energy $(H_f^i[V_pX_m])$ and its number of equivalent configuration $(\mathscr{D}_i[V_pX_m])$:

$$C_i[V_p X_m] \simeq \mathscr{D}_i[V_p X_m] \exp\left(-H_f^i[V_p X_m]/k_B T\right)$$
(1)

The general formulation of the formation energy (H_f) of each $V_p X_m$ cluster is expressed by:

$$H_{f}^{i}[V_{p}X_{m}] = E_{o}[(M-p)\cdot Al + m\cdot X] - E_{o}[M\cdot Al] + p\cdot\mu[Al] - m\cdot\mu[X]$$
(2)

where $E_o[(M - p).Al + m.X]$ and $E_o[M.Al]$ are the DFT energies of the system with and without a cluster (composed of *M* Al atoms), respectively. The chemical potentials (μ) were taken equal to the energy per atom either of the perfect structure for Al ($E_o[M.Al]/M$) or of the reference state of *X*. In the tables, H_f values were computed using $\mu[X] = E_o[ref]$ (see Appendix A). To compute concentrations, the temperature (T) and the chemical potential $-\mu[X] - ($ or the total concentration, $C_{tot}[X]$) are the free parameters of the equations.

The total vacancy concentration, $C_{tot}[V]$ and $C_{tot}[X]$ are thus given by:

$$\begin{cases} C_{tot}\left[V\right] = \sum_{p,m,j} p \cdot C_j\left[V_p X_m\right] \\ \overline{C_{tot}\left[X\right]} = \sum_{p,m,j} m \cdot C_j\left[V_p X_m\right]} \end{cases}$$
(3)

In the following discussions, we will also use the segregation energy of X in $V_p X_m$ ($E_{seg}[V_p X_m]$) expressed by:

$$E_{seg}[V_p X_m] = E_o[(M-p) \cdot Al + m \cdot X] + E_o[M \cdot Al] - E_o[(M-p) \cdot Al + (m-1) \cdot X] - E_o[M \cdot Al + X]$$

$$(4)$$

where $E_0[(M - p).Al + m.X]$ and $E_0[(M - p).Al + (m - 1).X]$ are the DFT energies of the V_pX_m and V_pX_{m-1} clusters, respectively. Segregation energy, not directly used in the thermodynamic model presented above, nevertheless allows us to provide information on atomic-scale processes. Indeed, it gives an idea of the affinity between a defect (here V_pX_{n-1}) and an isolated atom (X), and the possibility that it is trapped. We will therefore give this quantity in addition to the formation energy.

3. Ideal solubility

From first-principles calculations, we first discuss the formation energies of X in fcc-Al in the dilute limit, and analyze their relative stability. Three configurations were considered: the substituted, the tetrahedral (t, in 8c Wyckoff position) and the octahedral sites (o, 4b). The formation energies and the zero-point energies (ZPE)

Table 1

Formation energies (H_{f_i} in eV), zero-point energies (*ZPE*, in meV) and frequencies (ω_i , in cm⁻¹ and meV) of interstitial elements, the vacancy (labeled V) and the divacancies (V_2 : 1NN and 2NN, see text). The interstitial site that has the lowest energy is the energetically preferred one, it is shown in bold for each atom. Bader's charges (expressed in e⁻) and the number of electrons used in the pseudo-potential (in the brackets) are given. Elastic dipoles (\mathscr{P}_{ij} , in eV) and volumes of formation, Ω_f (in ua for the vacancies, or in Å³ for others) are also reported. In the case of 1NN and 2NN divacancies, there are two \mathscr{P}_{ij} values and three for the *M* configuration.

	site	H _f	ΔE	ZPE	ω		charge	\mathscr{P}_{ij}	Ω_{f}
-		eV	eV	meV	cm^{-1}	meV	e	eV	
v	13 44	0.632))	4 0	3 	-2.5	0.65
V ₂	1NN	1.324	-	-			1	$\begin{bmatrix} -4.9 & 0 & 0 \\ 0 & -4.9 & 0 \\ 0 & 0 & -4.6 \end{bmatrix}$	1.71
	2NN	1.253	~		æ	77.°	1. 7.	$\begin{bmatrix} -4.8 & 0 & 0 \\ 0 & -4.8 & 0 \\ 0 & 0 & -5.7 \end{bmatrix}$	1.77
Н	sub	1.806	1.089				unstable	_	
	t	0.717	0	+13	853	106	2.1 (1)	+2.1	4.8
	0	0.823	0.106	-68	420	52	2.3 (1)	+1.2	3.0
	М	1.099	0.383				unstable		
В	sub	2.399	1.170				unstable		
	t	2.413	1.184		unstable		5.3 (3)	+8.6	18.8
	0	1.229	0	-33	528	65	6.3 (3)	+5.1	11.1
	Μ	1.979	0.750				unstable		
С	sub	4.075	2.753				unstable		
	t	1.691	0.369	-66	572	71	6.6 (4)	+6.6	14.5
	0	1.322	0	-94	425	53	7.2 (4)	+2.8	6.4
	М	1.902	0.580	-82	775/281/209	96/34/26	7.1 (4)	$\begin{bmatrix} 9.4 & 2.7 & 0 \\ 2.7 & 9.4 & 0 \\ 0 & 0 & 0.7 \end{bmatrix}$	12.3
N	sub	3.040	3.944				unstable		
	t	-0.904	0	+27	550	68	7.3 (5)	+4.8	10.6
	0	-0.056	0.850	-29	253	31	7.7 (5)	+2.0	4.6
	Μ	0.222	1.125				unstable		
0	sub	0.066	3.544				unstable		
	t	-3.478	0	+24	389	48	7.8 (6)	+4.2	8.8
	0	-1.992	1.486		unstable		8.0 (6)	+3.3	6.9
1	Μ	-2.311	1.167				unstable		

are listed in Table 1. Within the harmonic approximation, the ZPE is expressed by:

$$ZPE = \sum_{i,q} \hbar \omega_{i,q} [\text{metal} + X]/2 - \sum_{i,q} \hbar \omega_{i,q} [\text{metal}]/2 - \sum \hbar \omega^{\text{ref}} [X]/2$$
(5)

where $\omega_{i,q}$ are the frequencies of *X* atoms inside the metal and $\omega^{\text{ref}}[X]$ are the frequencies of the reference states: for O, N and H atoms, we used the vibrations of O₂, N₂ and H₂ molecules respectively, in the case of carbon and boron, we used the diamond phase and the α -B12 structure respectively as reference states (see Appendix A.1). The frequencies of *X* in metal (ω_i), listed in Table 1, have a degeneracy of three.

As seen in a previous work [12], all species are located in interstitial and not in substitution sites. The formation energy of the substituted sites is almost 1-3 eV higher than the one of the other configurations, except for B atom, where the tetrahedral and substituted sites nearly have the same energy (see Table 1), same as in nickel [24]. However, frequency analysis shows that substituted positions are always unstable: there are always three imaginary frequencies for the X atoms. The species move from the ideal position and form vacancy-specie clusters, as we will see below.

Contrary to nickel [7,24], in which the most stable positions for all interstitial species are the octahedral sites, the most stable configuration in Al depends on the atom.

In the case of H atoms, we agree with Wolverton [25] on the fact that, at low temperature, the *t* site is the most stable configuration, when we take into account all relaxations, i.e., atomic and lattice relaxations and ZPE. The hydrogen solubility energy ($\simeq 0.73 \text{ eV}$) is in excellent agreement with earlier literature (see experimental

and theoretical references cited by Nazarov et al. [8]). The difference in energy between both sites is however very small: taking into account the zero-point energy, it is equal approximately to +25 meV. Similarly to hydrogen, we obtain that nitrogen is more stable in the tetrahedral positions than in the octahedral positions. However, the energy difference between both configurations (+0.90 eV) is higher for hydrogen.

O atoms prefer to be located in the *t* sites, the difference in energy (ΔE) with the *o* site is about 1.5 eV. Nevertheless, the analysis of O frequencies in the octahedral sites shows that this configuration is unstable: three imaginary frequencies were obtained. We looked for stable intermediate configurations by moving oxygen from the ideal *o* site. Nonetheless, the energy landscape seems to show that the only stable position is the tetrahedral site. If we move the O atom with a random displacement around the octahedral position, it moves towards the tetrahedral position. There is no additional intermediate site for O atoms.

For C atoms, the energy of the *o* site is significantly smaller than the one of the *t* site, approximately 0.37 eV. The ZPE does not change the relative stability, but slightly corrects the solubility enthalpy. However, contrary to literature results regarding fcc structures (except the recent work of David [12]), we found another stable position in the fcc-lattice for carbon. This position, labeled *M* (with the Wyckoff position 24d) in Table 1, is generally considered as the transition state between two first-nearest neighboring tetrahedral positions (but also between two octahedral positions, it is the same position). Nevertheless, *M* is less stable than *o* and *t* sites. In the case of H, O and N atoms, *M* sites always have two imaginary frequencies, but for carbon, *M* is a stable position.

For B atoms, results were similar to those obtained for oxygen: the stable positions are the octahedral sites, the ZPE is low and the *t*



Fig. 1. Contour maps of the Δ*ρ* electron density distribution of H, B, C and N atoms in an octahedral site (top) and H, C, N and O atoms in a tetrahedral site (bottom). Al atoms are depicted in black in the plane and in gray in the upper plane. The green circle represents the position of X atom.

sites are unstable. We also tested the *M* configuration for boron, without success: a calculation of the inter-atomic force interaction shows that this configuration has one imaginary frequency, *M* is the transition state in the diffusion process between two octahedral sites, see David et al. [12].

Finally, we report the results on mono-vacancies (V₁) and divacancies (V₂). In the case of V₂, two configurations were considered: the first- and second-nearest neighboring positions, labeled 1NN and 2NN, respectively. Our values (formation energies: 0.63, 0.66 and 0.62 eV per vacancy, and volumes of formation $\Omega_f = 0.65$, 0.85 and 0.88 u.a. per vacancy) are in agreement with previous studies [9,10,26]. 2NN is found slightly more stable than 1NN, with a negative binding energy between vacancies, this is consistent with results obtained by Wang et al. [27].

In order to analyze the interactions between the interstitials and the metal, we analyzed the charge transfer using the Bader's charge as well as the differential charge density distributions, $\Delta \rho = \rho [Al +$ $|X| - \rho[Al] - \rho[X]$. Results are summarized in Table 1 and plotted in Fig. 1, for octahedral and tetrahedral sites, only stable configurations are depicted. We used the same scale for all contour maps. We can see that all species acquire a part of the charge from the metal to partially fill their electronic shells: a positive charge transfer from the metal to the interstitial elements, from 1 to 3 electrons. In the case of B, C, N and O atoms, we clearly see that there is a charge transfer in the space between the solute and the first-nearest neighboring Al atoms, Al and X atoms form bonds. In the case of hydrogen, the charge transfer is different: it is mainly located around hydrogen. The electronic density-of-states (not depicted here) confirm these observations: H atoms, which have only s shells, interact foremost with the states at the bottom of the valence levels of Al contrary to other elements, where their p states interact with Al states. These results on the density-of-states are in agreement with those presented by Dai [28].

In the case of hydrogen, stability is partly controlled by the zeropoint energy, as already shown by Wolverton [25], which represents an important part of the solubility energy. However, in the case of other atoms, the ZPE is weak, so it is the competition between the elastic effects (measured through the volume of formation, elastic dipole, etc.) and the electronic interactions of the species with aluminum that seems to be responsible for the stability of the sites. It can be noted that there is a strong correlation between impurity electronegativity and site stability. The more the species is electronegative (as in the case of N and O atoms), the more it prefers to be in a tetrahedral site despite a strong elastic deformation.

To conclude on the general properties, we report the value of the elastic dipole (\mathcal{P}_{ij}) induced by the solutes in their stable configurations and the volume of formation (Ω_f , in Å³). As explained by Clouet et al. [29], the elastic dipole is the adequate quantity to characterize the elastic distortion induced by the insertion of a defect in the network, according to the elastic theory. In the case of o and t sites, the elastic tensor has only one component in the diagonal. For the other cases (M sites and divacancies), the tensor \mathcal{P}_{ij} contains several non-equal components and some off-diagonal elements, due to the symmetry break. All components are thus equal: $\mathcal{P}_{ij} = \delta_{ij}\mathcal{P}_{11}$. For 1NN and 2NN divacancies, we have two values, $\mathcal{P}_{11,22}$ and \mathcal{P}_{33} and in the case of M, there are three components. To compute these elastic dipole components, we used the following expression:

$$\mathcal{P}_{ij} = \sigma_{ij}/V.$$
 (6)

For different sizes of super-cells (up to 500 atoms), the volume was chosen equal to the equilibrium volume of the perfect structure (without defect) and afterwards only the atomic forces of the system with the impurity were relaxed. The strain σ_{ij} is then measured after atomic relaxations (DFT values). For each element or vacancy,



Fig. 2. Evolution of the elastic tensor \mathcal{P}_{ij} (in eV) as a function of the size of the supercell.

the evolution of the elastic tensor versus the size of the super-cell is depicted in Fig. 2 and the converged values are listed in Table 1.

Converged values are obtained for infinite box sizes. In our simulations, variations in P_{ij} can be observed for small boxes. They are related to the interaction of impurities in adjacent cells. We note also that in order to have relatively well converged values, it is therefore necessary to use large simulation boxes (> 200 atoms). It can then be assumed that the values given in the table are converged to 0.2 eV.

The value of \mathcal{P}_{11} is positive for all elements but negative in the case of the monovacancy. We also note that the evolution of \mathcal{P}_{11} from O to B atoms is not monotonic, neither is volume of formation. In the case of V₂, we note a small anisotropy: the value is twice as high as the monovacancy value, except for $\mathcal{P}_{33}[2NN - V_2]$. We see that in octahedral sites \mathcal{P}_{11} values are smaller than in tetrahedral sites. The stability of sites is a competition between elastic distortion of the lattice and electronic interactions (metal-X), this can be deduced by comparing elements.

In the light of these values, the lattice expansion, in the dilute limit, can be linked to the X concentration C[X] by using the following expression (interstitial elements induce hydrostatic strain):

$$a(C[X]) = a_o(1 + \delta \cdot C[X]) \tag{7}$$

with

$$\delta = \frac{4}{a_0^3} \frac{\mathscr{P}_{11}}{3B} = u \cdot \mathscr{P}_{11} \tag{8}$$

where *B* is the bulk modulus (approximately equal to 78 GPa) and a_0 the lattice parameter, equal to 4.04 Å. It gives, u = 0.041, \mathcal{P}_{11} is thus expressed in eV. Insertion increases the lattice parameter, while in the case of vacancies, it decreases.

4. Formation of X_m clusters

We hereinafter discuss the formation of clusters. We first consider the compact X_m clusters in a perfect crystal. For N, H and O (C and B) atoms, only tetrahedral (octahedral) positions were considered. DFT results are summarized in Table 2. In addition, initial configurations are displayed in Fig. 4.

We also considered an additional configuration for X_4 , in which X atoms are located in *o* sites and form a compact structure (case c): all X atoms are then in the first-nearest neighbor positions (1nn) with no Al atoms inside the pyramid formed by the X_4 cluster, contrary to the configuration (e), as represented in Fig. 4.

From a structural point of view, the relaxed positions are close to the ideal positions, interstitial atoms present small relaxations. Eq. (2) was used to compute formation energies ($H_f[X_m]$) and Eq. (4) used for segregation energies ($E_{seg}[X_m]$). By analyzing segregation energies we were able to identify which aggregate is likely to be formed at the atomic scale: a negative value means that the X_{m-1} cluster attracts one additional X atom to form X_m (see Fig. 3).

In the case of hydrogen, the ZPEs do not change significantly the energies (here, for simplification purposes only H atoms frequencies were computed). From X₂ configurations, we extracted X-X pair interactions (labeled ε_{X-X}^{nn}): for the octahedral positions, (b) and (a) correspond to the first- and second-nearest neighboring configurations (1nn and 2nn), respectively, and for the tetrahedral configurations, (c), (b) and (a) are the first-, second- and thirdnearest neighboring positions, respectively. Pair interactions can be used to build a generalized Ising model to study large clusters that cannot be obtained in DFT as illustrated in Refs. [3,30]. The pair interactions are thus directly equal to the segregation energies listed in Table 2. We see that all species can form small X_m clusters in aluminum ($E_{seg} < 0$). In the case of H, C and B atoms, ε_{X-X}^{1mn} is negative: it is equal to -0.06, -0.30 and -0.13 eV, respectively. The energy of the other (pair interaction) components can be considered equal to zero. In the case of N atoms, we obtain a positive value for ε_{X-X}^{1mn} (atoms repel), but a high negative value for ε_{X-X}^{2nn} (-0.26eV).

Table 2

Formation (H_f , in eV) and segregation energies (E_{seg} , in eV) of X_m clusters. In the case of hydrogen, the zero-point correction on the energy (H_{zpe} , in meV) and on the segregation energy (ZPE_{seg} , in meV) are also given. H, N and O atoms are in tetrahedral sites, and C and B atoms in octahedral sites. For X_2 the configuration c (b) for tetrahedral (octahedral) corresponds to the first-nearest position, see Fig. 5. In bold, we have highlighted the most stable configurations or those with negative segregation energies.

config	ţ	nitrogen	23	hydrogen	1			oxygen		carbon	3	boron	2
		H _f	Eseg	H _f	Hzpe	Eseg	ZPEseg	H _f	Eseg	H _f	Eseg	H _f	Eseg
X ₁	octa	-0.056	π.	0.823	-68	-		unstable	-	1.322		1.229	
	tetra	-0.904		0.717	13	<u>-</u>	-2	-3.478	-	1.691	-	unstable	-3
X ₂	a	-1.715^{3}	0.093	1.450 ³	36	0.017	11	-6.862^{3}	0.094	2.643 ²	-0.001	2.535 ²	0.078
	b	- 2.065 ²	-0.258	1.484 ²	20	0.051	-5	-7.193 ²	-0.237	2.337 ¹	-0.307	2.319 ¹	-0.138
	с	-1.434^{1}	0.373	1.366 ¹	23	-0.067	-3	-7.008^{1}	-0.052		-	ं जन्म	-
X3	a	-2.296	0.673	2.028	-97	-0.055	-132	-10.730	-0.059	3.339	-0.319	3.420	-0.128
	b	-2.619	0.350	2.140	-98	0.058	-133	-10.717	-0.049	3.030	-0.629	3.238	-0.309
	с	-3.461	-0.492	2.247	-115	0.164	-151	-11.124	-0.454	2 <u>—</u> 1		22	- <u></u>
X_4	a	-2.243	2.122	2.598	45	-0.147	130	-14.333	0.270	4.035	-0.316	4.366	-0.101
	b	-3.737	0.628	2.862	16	0.117	100	-14.810	-0.207	3.749	-0.603	4.161	-0.306
	с	-4.136	0.229	2.721	32	-0.023	116	-14.622	-0.019	3.445 ⁴	-0.906	3.957 ⁴	-0.510
	d	-3.476	0.889	2.861	61	0.117	145	-14.478	0.124	9 1 1		5 <u>-11</u>	
	e	-5.090	-0.725	3.111	8	0.367	92	-14.649	-0.046	3. 	1.77	100	
	f	-3.198	1.167	2.720	53	-0.024	137	-14.422	0.180	3 - 2			
X ₅	a	-4.529	1.465	3.318	46	0.003	-13	-18.311	-0.023	4.202	-0.868	5.007	-0.382
	b	-4.169	1.824	3.468	57	0.154	-2	-18.615	-0.327	343	-	5 44	
	с	-5.838	0.160	3.553	37	0.238	-22	-18.714	-0.426		-	-	-:
X ₆	a	-6.540	0.198	4.038	63	0.004	4	-22.657	-0.465	4.432	-1.092	5.826	-0.410
	b	-4.338	2.401	3.945	67	-0.089	8	-22.186	0.006	$i \longrightarrow i$	-	3 73	
	с	-4.665	2.072	4.120	90	0.086	31	-22.871	-0.680	9 -		5 4	
X7		-7.236	0.207	4.582	109	-0.079	29	-26.261	0.088	23 <u>-</u> 14	2 <u>25</u>	8 <u>22</u>	- - 2
X ₈		-2.342	5.798	5.203	138	-0.096	16	-29.446	0.294		100	8.00	(-))

1 1nn, ² 2nn and ³ 3nn configurations; ⁴ corresponds to the compact X₄ structure.



Fig. 3. Segregation energies of X_m , VX_m and V_2X_m (from top to bottom) clusters as a function of the number *m* of X atoms.



Fig. 4. : Schematic representation of VX_m configurations with their degeneracy. Only X atoms (black balls) and the vacancy (square) are represented. In the case of X_m clusters, we used the same configurations where the vacancy is filled by an Al atom. On top (bottom), we represent tetrahedral (octahedral) configurations formings a cubic (bi-pyramidal) structure around the vacancy.

For O atoms, ε_{X-X}^{1nn} and ε_{X-X}^{2nn} are both negative. Apart from oxygen (especially for large clusters), these pair interactions can reproduce X_m cluster energies without additional DFT calculations. These parameters are sufficient to reproduce X_m energies with a great accuracy.

One notes that H, C and B atoms can form large compact aggregates. The more *m* increases, the more stable C_m clusters are, and they are organized in a NaCl-like structure (see Appendix A.2). In the case of nitrogen, compact clusters are not preferred, but a structure emerges from DFT energies and pair energies. In this structure, each N atom is located in the second-nearest position of another N atom in the fcc lattice of Al. It corresponds to a zincblende structure. Experimentally, as explained in the introduction, there is only one intermediate alloy, the AlN structure. The difference in energy between both phases (zincblende and wurtzite) is low, but tends to favor wurtzite (see Appendix A.2). One can expect that for "high" concentrations, the zincblende structure transforms into the wurtzite phase.

In the case of O atoms, it is difficult to simply extract a general trend. Clusters are energetically stable (up to 6 O atoms in tetrahedral positions), but larger configurations are not favored. The pair interactions can not explain these results. However, as we will see below, such clusters should not exist from a thermodynamic point of view.



Fig. 5. o_1 and t_1 sites position in the cluster and O_b and T_b sites in the bulk.

5. Formation of VX_m clusters

We now investigate the interactions between a vacancy and one or several interstitial elements. As stated in previous works [1-4,7,31], we will see that some of them (H, O, B and C) interact with vacancies and can form VX_m clusters.

In previous works [5,9,10], aluminum has been used several times as reference system in the study of H clusters formation, but no studies have been carried out on other interstitial elements (C, N, O and B). Different positions were checked: either in the octahedral sites (labeled o_1) or in the tetrahedral (t_1) sites inside the first-nearest coordination sphere of the vacancy (see Fig. 5).

To look for intermediate positions, especially for low *m* values, we moved atoms from their ideal positions (o_1 and t_1) and towards the vacancy. We obtain only two stable positions: o_1 and t_1 , near the ideal position. Table 3 lists the formation and segregation energies of clusters. Results are depicted in Fig. 3.

As seen above, the substituted positions are energetically not preferred and unstable for all species studied, the vacancy is then restored and a vacancy-X pair is built.

In the case of N atoms, we find that for low N contents VN_i segregation energies are always positive: for both octahedral and tetrahedral sites and for any alternative position, contrary to what is observed in iron [3,32]. Nitrogen atoms and vacancies repel each other, thus preventing the formation of clusters. However, some clusters show negative segregation energies: VN_4 , VN_5 and VN_6 ,

Table 3

Formation ($H_{f_{f}}$ in eV) and segregation energies ($E_{seg_{t}}$ in eV) of V X_{m} clusters. In the case of hydrogen, the zero-point correction on the energy (H_{zpe} , in meV) and the segregation energy ($ZPE_{seg_{t}}$ in meV) are also given. The asterisk (*) means that the configuration is unstable (imaginary frequencies). In‡ configurations, we put one atom in the vacancy. Some configurations converge through the same cluster after relaxation, they are labeled "1", "2" and "3".

config			nitrogen		hydroge	n		14	oxygen		carbon	<i>1</i> 2	boron	
			H _f	Eseg	H _f	H _{zpe}	Eseg	ZPEseg	H _f	Eseg	H _f	Eseg	H _f	Eseg
X ₁	octa		-0.056	<u></u>	0.823	-68	570 1	<u>e</u> r:	unstable	175	1.322		1.229	-
	tetra		-0.904	3 55 2	0.717	13	100	ಡಚ	-3.478	. 	1.691	 .	unstable	1-6
VX_1	sub		3.040*	3.308	1.806*	-37	0.454	-50	0.066*	2.908	4.075*	2.118	2.399*	0.535
	octa		0.102	0.371	1.225	-105	-0.127	-118	-1.989	0.853	1.792	-0.165	1.889	0.025
	tetra		0.435	0.704	1.017	10	-0.335	-2	-2.926	-0.084	2.959	1.001	2.226	0.362
VX ₂	octa	а	-0.479	0.323	1.824	-208*	0.090	-232	-4.655	1.750	2.875	-0.238	3.136	0.013
		b	-0.612	0.189	1.828	-173*	0.095	-196	-5.155	1.250	2.779	-0.334	3.201	0.079
	tetra	a	0.176	0.977	1.402	16	-0.332	-7	-6.561	-0.156	3.517	0.399	5.990	2.867
		b	0.187	0.988	1.393	18	-0.340	-5	-6.578	-0.173	3.217	0.097	2.155	-0.967
		с	-0.115	0.686	1.437	35	-0.297	12	-6.368	0.037	2.996	-0.122	1.846	-1.276
VX ₃	octa	a	-1.354	0.162	2.424	-198*	0.314	-228	-7.971	2.085	3.698	-0.403	4.735	1.661
		b	-1.524	-0.008	2.429	-238	0.319	-268	unstable		3.598	-0.503	4.886	1.811
	tetra	a	-0.498	1.018	1.841	59	-0.269	28	-9.991	0.065	3.945	-0.162	2.252	-0.822
		b	-0.582	0.934	1.806	43	-0.303	12	-10.105	-0.049	3.880	-0.232	4.152	1.078
		с	-0.135	1.381	1.760	52	-0.350	20	-10.299	-0.243	5.184	1.083	2.783	-0.291
VX₄	octa	a	-2.252	0.175	3.025	-298	0.502	-353	-10.559	3.516	4.439	-0.480	6.339	2.858
•		b	-2.443	-0.015	2.587	-85*	0.064	-140	-13.121	0.953	4.368	-0.552	6.457	2.976
	tetra	а	-0.772	1.656	2.260	106	-0.263	51	-13.475	0.600	5.280	0.360	2.855 ³	-0.626
		b	-1.223	1.205	2.196	65	-0.327	10	-13.787	0.288	5.222	0.289	2.855 ³	-0.626
		с	-0.723	1.705	2.230	81	-0.293	25	-13.756	0.319	4.159	-0.769^{2}	3.486	0.005
		d	-1.008	1.420	2.199	65	-0.325	9	-13.743	0.332	5.532	0.574	4.063	0.582
		e	-0.480	1.948	2.114	40	-0.409	-16	-14.079	-0.004^{1}	8.353	3.433	3.882	0.401
		f	-0.987	1.441	2.237	81	-0.286	25	-13.627	0.448	5.493	0.574	3.416	-0.065
		gt	1.446	3.873	2.403	-100*	0.076	-145	-14.079	-0.004^{1}	4.159	-0.769^{2}	3.448	-0.033
VX5	octa	81	-3.515	-0.168	3.608	-308*	0.777	-360	-14.331	3.226	4.958	-0.514	8.083	3.010
	tetra	а	-1.512	1.835	2.636	123	-0.195	71	-17.266	0.291	6.558	1.085	5,192	0.118
		b	-2.812	0.535	2.611	103	-0.220	51	-17.357	0.199	6.671	1.171	4.578	-0.495
		c	-1.105	2.242	2.569	84	-0.262	32	-17.592	-0.035	5.567	0.095	4.558	-0.516
		d†	1 648	4 995	2 907	-	0.076		unstable	0.000	5 567	0.095	4 558	-0516
VXc	octa	4+	-4 726	-0 307	4 221	-416	0.936	-513	-16.830	4 2 3 9	5 4 1 5	-0.865	9 808	2 886
• • • •	tetra	а	_2 780	1 639	2 992	141	_0.293	44	_21 125	_0.056	8179	1 899	5.000	_1 852
	iciia	h	1 870	2 5 4 8	3 021	150	0.255	62	20.892	0 177	8/197	2216	5 172	1 750
		C ⁺	-1.070	2.340	3 004	130	-0.204	12	-20.032	0.177	8 021	1 7/1	5 200	-1.730
VV	octa	C ⁺	-1.104	1.065	4 500	155	-0.281	42	-21.055	0.057	7 756	1.741	J.200	-1.722
VA7	totra	2	-3.004	2 200	2 296	102	0.000	20	34 676	0.072	10 500	2 262	6 1 3 A	0 175
	tetta	d b+	-2.520	2.209	3.300 2.054	195	-0.525	22	-24.0/0	-0.075	10.399	2.002	C 095	-0.173
w	totra	nt	-1.724	3.903	3.834	-	0.145	21		0.000	12.026	J./Z/	0.980	1,000
VA8	tetra		-1.074	2.151	3./02	237	-0.541	21	-28.244	-0.090	15.950	2.015	0.345	-1.009

where N atoms are in o_1 . As we will see below, these configurations are not formed.

In the case of H atoms, we reproduce the segregation energies of clusters obtained in earlier works [8–10] on VH_m clusters. The most stable configurations inside the vacancy are the t_1 positions, as in the bulk. The segregation energies are almost constant, approximately equal to -0.300 eV, regardless the number of hydrogen atoms inside the cluster (see Fig. 3). The zero-point energy of H atoms, computed for all configurations, slightly modifies the segregation energies: from 10 to 100 meV, see Table 3. These simulations also enabled to show that some configurations are unstable (they have almost three imaginary frequencies), especially some VH_i clusters, with H atoms located in o₁ sites (configurations labeled by an asterisk (*) in the table). In addition, we tested configurations proposed by Lu et al. [9]. This was unsuccessful: H₂ molecules are less stable than dissociated elements inside the vacancy.

Contrary to nickel [7] where the binding energy between oxygen and vacancy is strong, in aluminum, there is a small attractive energy ($\varepsilon_{V-N}^{1mn} \approx -0.084 \text{ eV}$). From 1 to 3 oxygen in a vacancy, the segregation energy is slightly negative. We also observed that O atoms prefer to stay in a quasi-tetrahedral configuration. In some o_2 cases (for VO₄ and VO₃), O atoms move away from the vacancy. This last result is in agreement with our previous results showing that *o* sites are unstable for O atoms.

In the case of C atoms, the interaction with a vacancy energetically favors segregation. C atoms prefer to occupy the octahedral position o_1 , the pair interaction is equal to $\varepsilon_{V-C}^{1nn} \approx -0.165$ eV. The detailed analysis of relaxed configurations shows that in some cases (configurations labeled \ddagger in Table 3), when C atoms are in t_1 sites, new stable clusters are formed: in such configurations one C atom located in a t_1 site moves inside the vacancy. In such configurations, a diamond like structure (Fig. 4, VX₄, d configuration), the central atom forms bounds with other carbons. The same configurations were also studied for others elements, but results were inconclusive. DFT simulations indicate that VC₆ clusters could be formed.

Concerning the interactions between vacancies and B atoms, the situation is different. As for N atoms, small clusters (VB₁) are energetically unfavorable, but some configurations have strong negative segregation energies, especially VB₂, VB₃ and VB₄. Configurations with B atoms in o_1 positions are thermodynamically unfavorable. The most stable configurations are those where boron atoms are put in t_1 sites initially. However, contrary to other species where relaxed configurations are close to ideal positions, B atoms move greatly in the clusters. The reorganization around the vacancy is relatively high. Simple pair-interaction energies are thus inefficient to reproduce the interactions inside the vacancy.

Finally, as for X_m clusters, we extracted the pair-interaction energies ε_{V-X}^{1m} from VX clusters. For N atoms the value is always positive, and for H, C and O we obtain -0.33, -0.16 and -0.08 eV, respectively. The lowest pair-interaction is thus obtained for H atoms. As seen above, in the case of B atoms, a simple pairinteraction model is not accurate enough to capture the physics. The characteristics of large clusters can not be deduced from a simple model.

6. V₂X_m clusters

Finally, we report results on V_2X_m clusters. We explored the segregation of species in both divacancy configurations: 1NN and 2NN.

We studied octahedral and tetrahedral configurations but also "substituted" sites (*d* cases), corresponding to one of the two vacancies being occupied by an element. We also considered



Fig. 6. Schematic representation of $V_2 X_m$ configurations: tetrahedral sites in read and the octahedral sites in brown. The Od case corresponds to the "substitution" of one vacancy (V2, for example).

configurations where *X* atoms are between the divacancies (*e* and *c* for 1NN and 2NN, respectively). Configurations are displayed in Fig. 6. We inserted two segregation energies: the first one (E_{seg}^1) corresponds to the energy gain (loss) when adding one vacancy in VX (we considered the most stable VX configuration as reference state) and the second one (E_{seg}^2) corresponds to the energy gain (loss) when adding an *X* atom in V₂. Table 4 summarizes these results.

Similarly to VX clusters, N and O atoms segregate poorly in V₂ divacancies. The segregation energy is, at best, slightly negative. We can expect that these elements will not form V₂X_m clusters. On the contrary, there is an attractive interaction between H and V₂, equivalent to what is obtained for the monovacancy ($E_{seg}^2 \approx -300$ meV), and for C atoms some octahedral configurations remain stable. In the case of B atoms, V₂B_m are energetically less stable than VB_m.

Some additional V_2X_m configurations were explored, where m = 2 and 3, see Fig. 3. For H atoms the segregation is favorable, while for B and C atoms, the energy gain is low $(E_{seg}^2 < 0)$. We inserted these modified results into the statistical model but, since the melting point of Al is relatively low, these clusters will not appear in significant concentration.

7. Statistical approach

We now discuss the variation in defect concentrations as a function of X atom concentration and temperature by using the statistical approach described in part 2 and the formation energies given above. For simplification purposes, we did not present the results as a function of the chemical potential, $\mu[X]$. Indeed, for a given value of T, each value of $\mu[X]$ gives one value of total X concentration, $C_{tot}[X]$. We can thus plot independently the different results either as a function of $C_{tot}[X]$ or as a function of $\mu[X]$. The final

Table 4

Formation ($H_{f_{r}}$ in eV) and segregation energies of V₂X₁ clusters. E_{seg}^{1} (in eV) corresponds to the segregation energy of a vacancy in a V₁X₁ cluster, and E_{seg}^{2} (in eV) corresponds to the segregation energy of X in a V₂ divacancy. "Od = V2" means that one X atom occupies the vacancy.

config			nitrogen			hydroge	n				oxygen
			H _f	E ¹ _{seg}	E ² _{seg}	H _f	E ¹ _{seg}	E ² _{seg}	H _f	E ¹ _{seg}	E ² _{seg}
	X 1	octa	-0.056	_		0.823	_	_	unstable	_	_
	-	tetra	-0.904	_	_	0.717	_	_	-3.478	_	—
1NN	octa	Oa	0.800	0.062	0.379	1.719	0.067	-0.322	-1.292	0.999	0.861
		Ob	0.462	-0.276	0.042	1.713	0.060	-0.328	-1.925	0.366	0.229
		Oc	0.763	0.026	0.343	1.504	-0.148	-0.537	-2.104	0.187	0.050
		Od = V2	1.325	0.587	0.905	1.713	0.060	-0.328	-1.701	0.590	0.453
		Oe	1.080	0.342	0.660	1.719	0.067	-0.322	-1.704	0.587	0.450
	tetra	Ta	1.151	0.413	0.730	1.921	0.269	-0.120	-2.209	0.082	-0.055
		Tb	1.073	0.335	0.653	1.747	0.095	-0.294	-2.238	0.053	-0.084
		Tc	1.081	0.343	0.661	1.503	-0.149	-0.537	-1.766	0.525	0.388
2NN	octa	a	0.743	0.005	0.393	1.848	0.195	-0.122	-1.365	0.926	0.860
		b	0.681	-0.057	0.331	1.833	0.180	-0.137	-1.683	0.608	0.542
		с	0.689	-0.049	0.339	1.737	0.084	-0.233	-1.873	0.418	0.352
		d	0.741	0.003	0.391	1.845	0.193	-0.124	-1.329	0.962	0.896
	tetra	a	1.084	0.346	0.734	1.644	-0.009	-0.326	-2.268	0.023	-0.043
		b	1.066	0.328	0.717	1.677	0.025	-0.293	-2.225	0.066	0.000
config				carbon				boron			
				H _f	E ¹ _{seg}		E ² _{seg}	H_f	E ¹ _{seg}		E ² _{seg}
	X ₁		octa	1.322	_		_	1.229	_		-
			tetra	1.691	_		_	unstable	-		-
1NN	octa	L	Oa	2.496	0.068		-0.150	2.602	0.07	7	0.049
			Ob	2.599	0.172		-0.047	2.391	-0.1	134	-0.162
			Oc	2.395	-0.032		-0.251	2.446*	-0.0)78*	-0.106*
			Od = V2	3.188	0.761		0.542	2.916	0.39	2	0.364
			Oe	3.173	0.745		0.527	2.740	0.21	6	0.188
	tetra	a	Та	3.643	1.215		0.997	2.447*	-0.0)78*	-0.106*
			Tb	2.788	0.360		0.142	2.650	0.12	5	0.097
			Тс	3.174	0.747		0.528	2.739	0.21	4	0.186
2NN	octa	L	Oa	2.443	0.015		-0.132	3.033	0.50	8	0.551
			Ob	2.372	-0.055		-0.203	2.481	-0.0)44	-0.001
			Oc	2.704	0.277		0.129	2.736	0.21	1	0.254
			Od = V2	2.443	0.015		-0.132	3.030	0.50	5	0.548
	tetra	a	Та	3.566	1.139		0.991	2.656	0.13	1	0.174
			Tb	2.865	0.438		0.290	2.560	0.03	5	0.078



Fig. 7. Concentration of X atoms in each type of clusters calculated at three different temperatures (300, 600 and 900 K, from bottom to top) as a function of $C_{tot}[X]$. From left to right: H, C, N, O and B atoms. We plotted the concentration of X atoms in t and o sites (magenta), in X_m (green), VX_m (blue) and V_2X_m clusters (yellow) (For interpretation of the references to colour in this figure legend, the reader is referred to the web version of this article.).



Fig. 8. X_m cluster concentration at three different temperature (300, 600 and 900 K, from bottom to top) as a function of C_{tot}[X]. X₁ corresponds to the X concentration of t and o sites together. From left to right: H,C, N, O and B atoms.

results are depicted in Figs. 7 and 8.

Figs. 9 and 10 detail VX_m concentrations for H and B atoms. In the case of other species (C, N and O atoms), VX_m concentrations are considerably lower than the free vacancies, they are therefore not shown for simplification purposes.

Results, plotted in Fig. 7 enable to predict the form under which X atoms should be when located in aluminum: either alone (in octahedral or tetrahedral sites) or in clusters. For experimental concentrations (10-100 appm), O, N and C atoms are mainly located in X_m clusters at low T (green curves). The fraction of free atoms (magenta curves) corresponding to these three species is thus negligible. At high temperature (close to the melting point, i.e. 900 K), due to thermal effects, X_m are broken, species are free. To find X_m clusters at high T, very high concentrations of X would be required, beyond what is observed experimentally. Whichever the case, all three species (C, N and O) do not form clusters with vacancies, even at low temperature. The only clusters formed are X_m clusters. The vacancy concentration remains therefore unchanged, and is therefore fixed by thermal vacancies. On the other hand, the effect on vacancy concentration of the presence of H and B atoms is totally different: we can see that main defects are VX_m clusters (see Fig. 9 and 10). However, the consequences depend on the specie. B atoms always prefer to regroup in VB_m clusters. For H atoms, according to T, we obtain different results as we will see below.

More precisely, at low temperature, C_6 clusters are the main defects even at undetectable concentrations (see Fig. 8). When T increases, the transition (in $C_{tot}[C]$) between large clusters and the free state decreases. We can therefore expect that at high T and experimental concentration (< 100 appm), clusters are dissolved. Hence, C atoms should be located only in *o* sites. In addition, despite negative values of segregation energy for some VC_m clusters, the high stability of C_m implies that C atoms will preferentially form clusters without a vacancy.

These results should be looked at carefully. In our statistical model, at low temperature and for high values of $C_{tot}[X]$, the major clusters are the largest X_m clusters considered by the model, so that all carbon atoms are located in these clusters. We reach here the

limitations of our approach. At this level of approximation, only small clusters are included: those composed of 6 or fewer atoms, see Fig. 8. We have developed a general statistical model that can include all cluster sizes, but in the first-order approximation and due to the constraints of our approach, we only considered small clusters. The case of C atoms (small clusters) points out the limits of our approximation. If we wanted to improve the physical description of our system, we should adopt an approach including clusters of all sizes. However, these results allow for a reasonable assumption stating that the limit of solubility of these elements is very low. This is consistent with experimental findings: when carbon concentration becomes too "high", C_m clusters are formed and C atoms precipitate.

A similar analysis can be made for N atoms: nitrogen forms N_m clusters only at low T (around 300 K) and is free at higher temperatures. Once again, our results state that the nitrogen solubility is low. Our model predicts that for a high concentration of nitrogen, large amounts of N_m will be formed, which should lead to the precipitation of AlN.

The physics of oxygen in Al is completely different from what has been observed in nickel [7] and iron [4]. In these systems, the strong interaction between vacancies and O atoms induces that O atoms form clusters even at high T. In Al, we showed that the interaction between O and vacancies are weak. At high T (above 600 K and at experimental concentrations), we therefore found that O atoms are located in tetrahedral sites. There are no clusters with vacancies. At low temperature, O concentration is significantly low and O atoms are to be located in interstitial position only. However, unlike what was found for C atoms, and even though it is difficult to extrapolate the formation energies of large O_m clusters, it is expected that these clusters will not change the relative concentration of the different clusters and modify the final result being that O atoms are mainly located in tetrahedral sites.

For H and B atoms, one expects that the concentration of clusters with vacancies will become not negligible, see Fig. 9. In the case of hydrogen, above 600 K, H atoms remain predominantly alone in interstitial position (see Figs. 7 and 8), i.e. in the tetrahedral



Fig. 9. Vacancy concentration at three different temperatures (300, 600 and 900 K, from bottom to top). From left to right: H and B atoms. The dashed lines represent the concentrations obtained with the experimental value of the vacancy.

position and VX_m are dissolved. When the temperature drops (above 600 K), the vacancy concentration increases significantly in the presence of H atoms, even though most of H atoms remain free, exactly what is observed in nickel [1,31]. Nonetheless, in these conditions, while the concentration of VH_m clusters is many orders of magnitude higher than thermal concentrations, these larger clusters do not influence the total concentrations of defects. At intermediate temperatures (600 K) and experimental H concentrations (< 1000 appm), VH₁ and VH₂ are the main clusters (Fig. 10). Their concentrations are 1-2 orders of magnitude higher than thermal vacancy concentration. At low T (300 K), there is a change as we can see on Fig. 7. In the range of $[10^{-6}; 10^{-4}]$ H concentration. the amount of clusters increases significantly, to reach a maximum (above 10^{-4}) when all H atoms are located in VH_n clusters (see Figs. 7 and 9). In this case the nature of the predominant defects depends on the hydrogen concentration (see Fig. 10): from the VH₁ cluster for low concentrations (10^{-6} , i.e. 1 appm) to VH₆ for high concentrations $(10^{-3}, i.e. 1000 \text{ H appm})$. This result agrees with earlier results [5].

If we include multi-vacancy clusters, the concentration of V_2H_m clusters remains always many orders of magnitude lower than the concentration of VH_m defects and can therefore be neglected (see Fig. 9). The maximal effect is at low T (300 K), where full filled

vacancies (VH₆) have large concentration for usual H concentrations. We clearly see that even if VH_m should move slowly like in nickel [33], the abundance of vacancies will affects the diffusion of species in aluminum.

In the case of B atoms, the physics is different. We note that $C[VB_m]$ is higher than those of other clusters, and especially of free atoms, see Fig. 9. B atoms always aggregate and form clusters with a vacancy (see Fig. 7). A small content of B atoms therefore induces an important vacancy concentration, the same order of magnitude than B concentration. As suggested by our DFT values, one notes that main clusters are the VB₃ and VB₄.

8. Conclusion

In conclusion, we investigated the solubility of carbon, nitrogen, hydrogen, boron and oxygen in aluminum by using a multi-scale approach. DFT simulations of isolated atoms and clusters enabled us to: (i) show that C and B atoms prefer to be located in octahedral sites, while O, H and N atoms prefer tetrahedral sites. The insertion of species in such positions (Bader charge, elastic dipole, solubility energies ...) within the metal have been fully characterized. (ii) In the case of C atoms, we identified one new position, which is nevertheless less stable than the octahedral site. O and B atoms



Fig. 10. VX_m cluster concentration at three different temperature (300, 600 and 900 K, from bottom to top). From left to right: H and B atoms. The dashed lines represent the concentrations obtained with the experimental value of the vacancy. The thick dashed lines are the total vacancy concentrations $C_{tot}[V]$.

only have one stable position each: t and o sites, respectively. (iii) From the study of interactions (X-X, V-X and V₂X), including large clusters, we see that some clusters are stable either under the form of X_m (in the case of C, N and O atoms) or VX_m clusters (H and B atoms). Pair interaction energies are also reported, directly useful for a Hamiltonian approach. These data characterize interactions between the metal and interstitial elements.

To capture the thermal effects, we used a statistical approach that includes DFT energies of the different types of clusters: X_m , VX_m and V_2X_m . We show that at high temperature C, N, O and H atoms are in interstitial positions. Our results show that these atoms do not modify significantly the vacancy concentration, contrary to what was found for B atoms. At low T, the physics changes: for carbon, oxygen and nitrogen form preferentially X_m clusters, whereas hydrogen atoms are in *t* sites but VH_m concentrations are high. Regarding B atoms, they always form clusters with a vacancy.

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Appendix A. References states and alloys of Al

Appendix A.1. Diamond and boron structures

To evaluate the Helmholtz energy of carbon diamond, we calculated the inter-atomic force constants using the finite displacement approach. They were calculated displacing only non equivalent atoms along non equivalent directions according to the symmetry of the system. The *phonopy* package [23] was used to generate finite displacements according to the symmetry of each structure. It was then used to analyze and compute vibrational properties. A $3 \times 3 \times 3$ super-cell (54 atoms in the unit-cell) was used and only one finite displacement is necessary for diamond.

In the case of boron, we used the hR12 structure, space group No 166. There are two types of atoms B-I and B-II that occupy the same (6 h) sites (u_1 , u_1 , u_2). This structure was used as a reference state, even the β -B [34] (space group No 166) and the B t-50 (space group No 134, where B atoms are in 2b, 8m, 8m, 16n and 16n) structures are often referred as more stable. Table A.1 summarizes these results.

Table A.1		
Formation energies (<i>E</i> _f , in eV/at	tom), lattice parameters (in Å) of different Al-compounds.

structure		ao	Co	ui	Ef
Al (fcc)		4.04	-	4) (0
	[35]	4.04	2 	2 33	
C (diamond)		3.574	5 <u>-</u>		0
	[35]	3.567	2.77	1. 	
Β(α)		2.828	4.182	0.010/0.654	0
				0.221/0.630	
Β (β)		11.073	23.804	7	0.135
	[18]	10.925	23.814		
B (t-50)		8.838	4.952	3-34	0.097
WZ	AlO	3.689	6.101	0.350	-1.684
	AlN	3.128	5.015	0.381	-1.413
	[13]	3.111	4.979		
ZB	AlO	2.266	3 — 3	3	-1.711
	AlN	2.198	11	(-)))	-1.392
NaCl	AIC	4.268			+0.421
	AlB	4.542			+0.623
Al ₂ O ₃		5.177	55°29	0.352/0.943	-3.026
	[14]	5.127	55°16		-2
Al ₄ C ₃		3.353	25.117	0.129/0.293	-0.152
				0.217	
	[36]	3.335	24.059	0.129/0.294	
				0.217	
AlB ₂		3.008	3.288	5 3/	-0.043
-	[18]	3.006	3.252	i n i	1 = 2

Appendix A.2. Aluminum alloys

Finally, we conducted additional calculations on several Al-X alloys: the wurtzite (WZ, hP4, space group $P6_3mc$), where Al atoms are located in 2b (1/3, 2/3, 0) and X in 2b (1/3, 2/3, u), the zincblende structure (ZB, cF8, space group $F\overline{4}3m$) where Al atoms are in 4a (0, 0, 0) and X in 4c (1/4, 1/4, 1/4) and the NaCl structure (cF8, space group $Fm\overline{3}m$) where Al atoms are in 4a (0, 0, 0) and X in 4c (1/4, 1/4, 1/4) and the NaCl structure (cF8, space group $Fm\overline{3}m$) where Al atoms are in 4a (0, 0, 0) and X in 4b (0.5, 0.5, 0.5). We also reported results for additional structures: (i) the corundum Al₂O₄ structure (hR10, space group $R\overline{3}c$), where Al atoms are in 4c (u_1 , u_1 , u_1) and O in 6e (u_2 , $1/2-u_2$, 1/4); (ii) the Al₄C₃ structure (hR7, space group $R\overline{3}m$) where Al atoms are in two 6c (0, 0, $u_{1,2}$) and C in 6c (0, 0, u_3) and 3a (0, 0, 0) [36]; and (iii) the AlB₂ structure (ω phase, hP3, space group P6/mmm), where B atoms are in 2d (1/3, 2/3, 1/2) and Al in 1a (0, 0, 0).

The NaCl structure corresponds to an fcc structure in which all octahedral sites are occupied. The AlX zincblende is an fcc-Al where half of the tetrahedral sites are occupied. Table A.1 summarizes these results. DFT results are in excellent agreement with experimental values (lattice parameters and Wyckoff positions) for AlN wurtzite, Al₂O₃, Al₄C₃ and AlB₂. One can notice that experimental structures are always the more stable structures.

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